

### **General Description**

The operating voltage range of the single inverter is 1.65V to 5.5V.

The HSN74LVC1G04 device contains single inverter and performs the Boolean function Y=A.

The CMOS device has high output drive while maintaining low static power dissipation over a broad Vcc operating range.

This device is fully specified for partial-power-down applications using loff.

The loff circuitry disables the outputs, preventing damaging current back flow through the device when it is powered down.

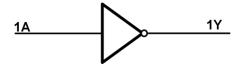
#### **Features**

- Low power consumption,10-µA max I<sub>CC</sub>
- Supports 5V V<sub>CC</sub> operation
- Inputs accept voltages to 5.5 V
- Max tpd of 3.3 ns at 3.3V
- ±24-mA output drive at 3.3V
- loff supports partial-power-down mode
- Typical VoHv > 2V at Vcc = 3.3V, TA = 25°C
- Typical Volp < 0.8V at Vcc = 3.3V, TA = 25°C</p>

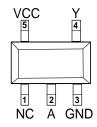
# **Applications**

- AV receivers
- Audio docks: portable
- Blu-ray players and home theater
- Embedded PC
- MP3 player/recorder (portable audio)
- Personal digital assistant (PDA)
- Power: telecom/server AC/DC supply
- Solid state drive (SSD):
   client and enterprise TV: LCD/
   digital and high -definition (HDTV)

# **Functional Block Diagram**



#### **Pinning and Pin Functions**





SOT-23-5L/SC-70-5

	Pin	Tyro	Decarintian
Name	SOT-23-5L/SC-70-5	Туре	Description
NC	1	_	No internal connection
Α	2	I	Input
GND	3	_	Ground
Υ	4	0	Output
VCC	5	_	Positive Supply



# **Absolute Maximum Ratings**

	Parameters	Min	Max.	Unit	
Vcc	Supply voltage	e range	-0.5	6.5	V
Vı	Input voltage	range	-0.5	6.5	V
Vo	Voltage range applied to any output in the	high-impedance or power-off state	-0.5	6.5	V
Vo	Voltage range applied to any out	-0.5	V <sub>CC</sub> +0.5	V	
I <sub>IK</sub>	Input clamp current	V <b>&lt;</b> 0		-50	mA
Іок	Output clamp current	Vo<0		-50	mA
lo	Continuous outp	out current		±50	mA
	Continuous current through	Vcc or GND		±100	mA
TJ	Junction temperature under bias			150	°C
T <sub>stg</sub>	Storage tempera	ture range	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# **Recommended Operating Conditions**

Over operating free-air temperature range (unless otherwise noted)

Symbol	Parai	meter	Min	Max	Unit
Vcc	Supply	voltage	1.65	5.5	V
Vı	Input v	<i>r</i> oltage	0	5.5	V
Vo	Output	voltage	0	Vcc	V
		V <sub>CC</sub> =1.65V		-4	
	loн High-level output current	Vcc=2.3V		-8	
Іон				-16	mA
		V <sub>CC</sub> =3V		-24	-
		Vcc=4.5V		-32	
		V <sub>CC</sub> =1.65V		4	
		Vcc=2.3V		8	
loL	Low-level output current	\/ -0\/		16	mA
		V <sub>CC</sub> =3V		24	
		V <sub>CC</sub> =4.5V		32	
T <sub>A</sub>	Operating free-	air temperature	-40	125	${\mathbb C}$

# **ESD Ratings**

	E	Value	Unit	
\//EQD\	Electrostatic discharge	Human-body model (HBM)	6 K	V
V(ESD)	Electrostatic discharge	Charge device model (CDM)	2 K	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



# **Thermal Information**

Package Type	<b>Ө</b> ЈА	<b>0</b> .c	Unit
SOT-23-5L	250	81	°C/W
SC-70-5	400	150	°C/W

#### **Electrical Characteristics**

Vcc=5.0V or 3.3V, FULL=-40°C to +125°C, Typical values are at TA=+25°C. (unless otherwise noted)

<b>D</b>		Took Oo walking	.,	-4	0°C to 85	°C	-40	)°C to 12	5°C		
Parameter		Test Conditions	Vcc	Min	Тур	Max	Min	Тур	Max	Un	
		Ι <sub>ΟΗ</sub> =– 100 μΑ	1.65 V to 5.5 V	Vcc-0.1			Vcc-0.1				
		I <sub>OH</sub> =-4 mA	1.65 V	1.2			1.2				
.,		I <sub>OH</sub> =-8 mA	2.3 V	1.9			1.9				
V	OH	I <sub>ОН</sub> =— 16 mA	3 V	2.4			2.4			\ \	
		I <sub>OH</sub> =-24 mA	3 V	2.3			2.3				
		I <sub>он</sub> =–32 mA	4.5 V	3.8			3.8				
		I <sub>OL</sub> =100 μA	1.65 V to 5.5 V			0.1			0.1	l	
		I <sub>OL</sub> =4 mA	1.65 V			0.45			0.45	<del>1</del> 5	
		I <sub>OL</sub> =8 mA	2.3 V			0.3			0.3	,	
V	OL	I <sub>OL</sub> =16 mA	0.17			0.4			0.4	\	
		I <sub>OL</sub> =24 mA	3 V			0.55			0.55		
		I <sub>OL</sub> =32 mA	4.5 V			0.55			0.55		
l <sub>l</sub>	A input	V⊨5.5 V or GND	0 to 5.5 V			±5			±5	μ	
I	off	V <sub>I</sub> or V <sub>O</sub> =5.5 V	0			±10			±10	μ	
lcc		V <sub>i</sub> =5.5 V or GND, I <sub>0</sub> =0	1.65 V to 5.5 V			10			10	μ	
ΔΙ	CC	One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 5.5 V			500			500	μ	
(	G	V <sub>i</sub> =V <sub>CC</sub> or GND	3.3 V		5			5		р	

<sup>(1)</sup> All unused digital inputs of the device must be held at Vcc or GND to ensure proper device operation.

# Vcc=5.0V or 3.3V, FULL=-40°C to +125°C, Typical values are at TA=+25°C. (unless otherwise noted)

						–40°C t	o 125°C				
Parameter	From (Input)	To (Output)	V <sub>CC</sub> = ± 0.	1.8 V 15 V	V <sub>CC</sub> =:	-	V <sub>cc</sub> =3 ± 0.	-	V <sub>CC</sub> = ± 0.	-	Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pd}$	A	Y	3.9	8.0	1.4	3.5	1	3.3	1	3.0	ns

# T<sub>A</sub>=25°C

Ī	Parameter		Took Conditions	V <sub>cc</sub> =1.8 V	V <sub>CC</sub> =2.5 V	V <sub>CC</sub> =3.3 V	V <sub>CC</sub> =5 V	l l = #
			Test Conditions	Тур	Тур	Тур	Тур	Unit
	$C_{pd}$	Power dissipation capacitance	f=10 MHz	17	18	25	30	pF

# **Typical Characteristics**

Over recommended operating free-air temperature range, C<sub>L</sub>=30 pF or 50 pF (unless otherwise noted).

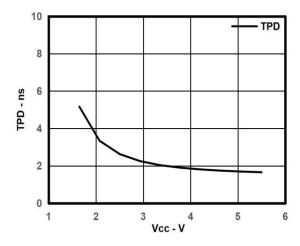


Fig.8-1. Typical Tpd vs Vcc

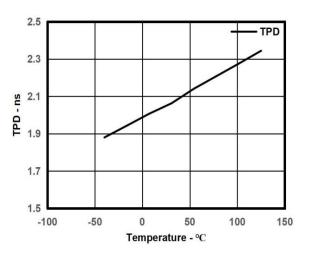
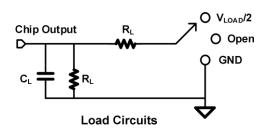


Fig.8-2. Typical Tpd vs Temp

#### **Parameter Measurement Information**

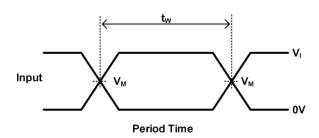


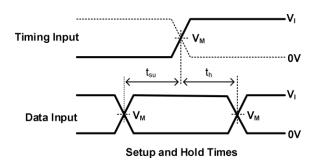
TEST	S1
T <sub>PHL</sub> /T <sub>PLH</sub>	OPEN
T <sub>PLZ</sub> /T <sub>PZL</sub>	$V_{LOAD}$
T <sub>PHZ</sub> /T <sub>PZH</sub>	GND

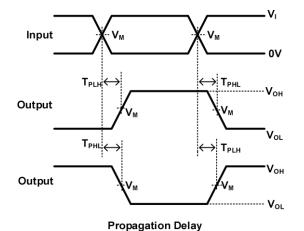
# **Parameter Measurement Information(Continued)**

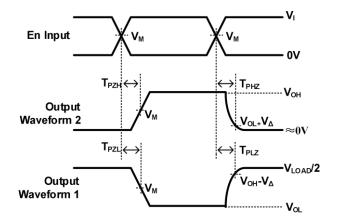
V	INPUTS		V	V	C	D	V <sub>∆</sub>	
Vcc	Vı	T <sub>f</sub> /T <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	C∟	R∟	<b>ν</b> Δ	
1.8V±0.15V	Vcc	≤2ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30pF	1kΩ	0.15V	
2.5V±0.15V	Vcc	≤2ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30pF	500Ω	0.15V	
3.3V±0.15V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V	
5V±0.15V	Vcc	≤2.5ns	Vcc/2	2×V <sub>CC</sub>	50pF	500Ω	0.3V	











Notes: A. C<sub>L</sub> includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.

for Output and Inverted Output

D. The outputs are measured one at a time, with one transition per measurement.

**Enable and Disable Times** 

Low-And High-Level Enabling

E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.

Waveform 2 is for an output with internal conditions such that the F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ . output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR 10 MHz, Z =50.

- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all device.

#### **Detailed Description** Overview

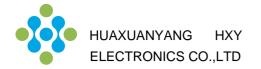
This device is fully specified for partial-power-down applications using loff. The loff circuitry disables the outputs, preventing damaging current back flow through the device when it is powered down.

#### **Feature Description**

The device is designed for 1.65V to 5.5V V<sub>CC</sub> operation and it allows down voltage translation from 5V to 3.3V, or 3.3V to 1.8V. Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value. Ioff feature allows voltages on the inputs and outputs, when Vcc is 0 V.

#### **Device Functional Modes**

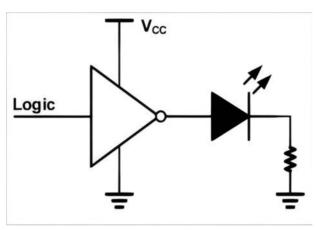
Input A	Output Y
Н	L
L	Н



# **Application Information**

The HSN74LVC1G04 is a high drive CMOS device that can be used for implementing inversion logic with a high output drive, such as an LED application. It can produce 24mA of drive current at 3.3V making it Ideal for driving multiple outputs and good for high-speed applications up to 100Mhz. The inputs are 5.5V tolerant allowing it to translate down to Vcc.

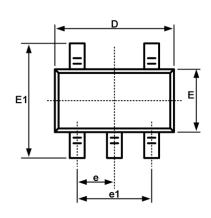
# **Typical Power Button Circuit**

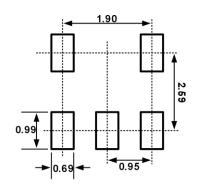


# **Order information**

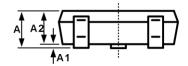
Package	Package Orderable Device	
SOT-23-5L	HSN74LVC1G04DBVR	3000/Reel
SC-70-5(SOT-353)	HSN74LVC1G04DCKR	3000/Reei

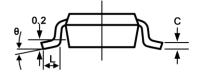
# Package Outline SOT-23-5L





Recommended Land Pattern (Unit: mm)

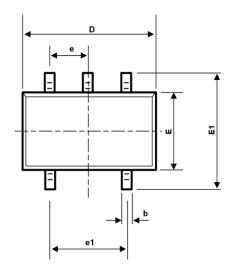


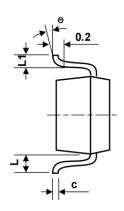


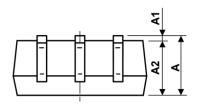
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950BSC		0.037BSC	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
L1	0.600REF		0.024REF	
θ	0°	8°	0°	8°



# Package Outline SC-70-5







symbol	Dimension In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
С	0.110	0.175	0.004	0.007
D	2.000	2.200	0.079	0.087
Е	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°



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